Phase transformations at interfaces: Observations from atomistic modeling

T. Frolov, M. Asta, Y. Mishin

Lawrence Livermore National Laboratory, Livermore, CA 94550, USA

Department of Materials Science and Engineering, University of California, Berkeley, CA 94720, USA

Department of Physics and Astronomy, MSN 3F3, George Mason University, Fairfax, VA 22030, USA

ABSTRACT

We review the recent progress in theoretical understanding and atomistic computer simulations of phase transformations in materials interfaces, focusing on grain boundaries (GBs) in metallic systems. Recently developed simulation approaches enable the search and structural characterization of GB phases in single-component metals and binary alloys, calculation of thermodynamic properties of individual GB phases, and modeling of the effect of the GB phase transformations on GB kinetics. Atomistic simulations demonstrate that the GB transformations can be induced by varying the temperature, loading the GB with point defects, or varying the amount of solute segregation. The atomic-level understanding obtained from such simulations can provide input for further development of thermodynamics theories and continuous models of interface phase transformations while simultaneously serving as a testing ground for validation of theories and models. They can also help interpret and guide experimental work in this field.

1. Introduction

Recent years have seen a rapid growth of evidence suggesting that materials interfaces are capable of first-order structural transformations in which the interface properties (such as solute segregation, excess volume, mobility or sliding resistance) undergo discontinuous changes [1]. Experiments have revealed a potentially important role of grain boundary (GB) phase transitions (sometimes referred to as “compensation transitions” [1,2]) in abnormal grain growth in ceramics [2], activated sintering [3] and liquid metal embrittlement [4]. Layering transitions associated with GB segregation were investigated using lattice gas models [5,6], first-principles calculations [7] as well as advanced electron microscopy and spectroscopy methods [8–10]. Experimental investigation of the potential impact of GB phase transitions on microstructure and other materials properties is currently a highly active area of research [1,4,11–13]. The experimental studies have raised a number of fundamental questions concerning the thermodynamic nature of the interface phases, their atomic structures and kinetic properties. A unified thermodynamic description of bulk and low-dimensional phases has been recently proposed [14], phase rules for phases of any dimensionality have been formulated, and adsorption equations for interface phases and line defects separating such phases have been derived [14]. Phase-field models have been developed [2,15,16], predicting a variety of possible interface transformations and mapping them onto bulk phase diagrams. Although fundamentally important, the thermodynamic analysis [14,17–19] and phase-field models [2,15,16] do not provide atomic-level insights into interface phases and phase transformations. The goal of this paper is to review the recent progress in atomistic modeling of interface transformations, focusing on GBs in metallic systems as an important practical case. Although molecular dynamics (MD), Monte Carlo (MC) and other atomistic simulation methods have been successfully applied to study interfaces for a long time [20,21], it has not been until very recently that it became possible to identify and structurally characterize individual GB phases, compute their thermodynamic properties, and observe transformations among them. We describe the recent work on structural transformations in single-component GBs (Section 2), in binary alloys (Section 3), and the effect of such transformations on GB migration and short-circuit diffusivity (Section 5). In Section 5 we discuss existing challenges in this field and outline future work.

2. Grain boundary phase transitions in pure metals

2.1. The multiplicity of ground-state grain boundary structures

Atomistic computer simulations have proven to be an invaluable tool for the study of GB properties [21]. Such simulations have
been successfully applied to predict GB structures and calculate their thermodynamic and kinetic properties, such as GB free energies, diffusivities and mobilities as functions of temperature and chemical composition [21–30]. However, despite the extensive research, there has been no convincing simulation evidence of GB phase transformations until very recently (except for the dislocation-pairing transition in relatively low-angle GBs [31]). It has been demonstrated that the critical impediment to observations of such transformations was rooted in inadequate simulation methodology, namely, in fixing the total number of atoms and using periodic boundary conditions. In order to sample all possible atomic configurations, atoms need to be added to or removed from the GB region [32–36]. To overcome this shortcoming of the atomic configurations, atoms need to be added to or removed using periodic boundary conditions. In order to sample all possible methodology, namely, in fixing the total number of atoms and

periodic boundary conditions and a fixed number of atoms cannot be applied. To enable automatic adjustment of the atomic density during the transformation, a different methodology has been proposed in which one or both edges of the GB terminates at an open surface (Fig. 2(a)). In this setup, provided the temperature is high enough, atoms can leave or enter the GB by diffusion to/from the surface. This effectively makes the GB an open thermodynamic system capable of exchanging atoms with a reservoir, a condition which naturally exists under experimental conditions.

As an example, Fig. 2(a) shows a Cu bicrystal with the Σ5(310) boundary annealed at 800 K (0.6Tm, Tm = 1327 K being the melting temperature predicted by this potential) for tens of nanoseconds. The zoomed-in views reveal the original normal-kite GB structure on the left and a new, split-kite structure on the right. The latter nucleates at the surface and gradually propagates inside the bicrystal during the simulation. Its growth is enabled by the supply of extra atoms from the surface, a process which is kinetically controlled by GB diffusion. At a certain temperature, the two GB phases can coexist in thermodynamic equilibrium separated by a line defect representing a one-dimensional phase boundary between two two-dimensional phases. Knowledge of thermodynamic and topological properties of these unusual defects is important for the understanding of GB phase transitions (particularly, GB phase nucleation). These defects deserve a detailed study in the future. The observation of coexistence of GB phases with different densities separated by an atomic-width line defect confirms that the phase transformation is first order in character. Similar fully reversible temperature-induced phase transitions were found in the Σ5(210) boundary [37].

2.3. Grain boundary transitions induced by point defects

During GB phase transformations, the boundary absorbs or rejects a large amount of atoms. This suggests that a phase transformation can be induced by injection or removal of a suitable number of point defects at a fixed temperature. This was indeed confirmed by simulations in which a GB phase was initially created in a periodic supercell isolated from external sources or sinks of atoms as in Fig. 3(a). A number of vacancies or interstitial atoms was then introduced into the GB region and the system was re-equilibrated by an MD run. For example, 80 interstitial atoms (the number required for transformation to the split-kite phase) were introduced into the normal-kite structure of the Σ5(310) GB followed by an anneal at 800 K. A possible outcome could be a uniform redistribution of the extra atoms in the initial GB structure. Instead, a first-order transformation to the split-kite phase was observed as illustrated in Fig. 3(c). This transformation was fully reversible: when the same number of vacancies was subsequently introduced into the split-kite phase, the latter transformed back to normal kites (Fig. 3(e)). As a result of this phase transformation cycle, the boundary returned to its initial state having annihilated a large number of point defects. Analogous transformation cycles were observed upon loading of point defects into the Σ5(210) GB.

These simulations suggest that interfacial phase transformations can greatly increase the capacity of GBs to absorb non-equilibrium point defects. This finding may have important practical implications for materials operating under extreme conditions. For example, the radiation tolerance of many nuclear materials depends on the efficiency of GBs as sinks of vacancies and interstitials created during irradiation by energetic particles [40–43]. GB phase transformations present a novel mechanism of radiation damage healing in such materials.

3. Segregation-induced grain boundary transitions

In technological applications, dopants and impurities can play a dominant role in microstructure evolution and properties. Recent experimental studies of doped ceramics revealed discontinuous
changes in coarsening behavior that were attributed to the emergence of GB phases \[1,2,13\]. Such phases are characterized by different segregated structures such as a monolayer, a bilayer, a trilayer, or a thick disordered layer \[4,12\]. Recent atomistic simulations have provided insights in the thermodynamic origin and physical mechanisms responsible for phase transitions in segregated GBs \[22,38\].

3.1. Segregated grain boundary structures

The choice of the \(\Sigma 5(210)\) GB in Cu-rich Cu-Ag alloys as a model system to study segregation effects was prompted by the recent experimental measurements of Ag diffusion in this boundary \[39\] and the availability of a reliable interatomic potential reproducing the Cu-Ag phase diagram \[44\]. The study combined MD with
3.2. Segregation effect on grain boundary transformations

In pure Cu, the transition between the split-kite and filled-kite phases of the Σ5(210) GB occurs at a temperature of about 1050 K [37]. The segregation isotherms indicate that at the temperature of 900 K (when the split-kite phase in pure Cu is more stable), Ag segregation into filled kites increases with the grain composition $c$ faster than does the segregation into split kites (Fig. 4(d and f)). From the Gibbs adsorption equation, we can conclude that the free energy $\gamma_{SK}$ of filled kites decreases with the grain composition faster than does the free energy $\gamma_{SK}$ of split kites. One can expect, therefore, that at some composition $c$, the two free energies become equal, $\gamma_{SK} = \gamma_{SK} = \gamma_{c}$, and a segregation-induced phase transformation occurs.

To test this prediction, a simulation block with two open surfaces was utilized (Fig. 4(a)). MC simulations were conducted at 900 K for a set of grain concentrations imposed by different diffusion potentials $M$. The boundary was initially composed of two phases separated by a phase junction. During the simulations, one of the phases always grew while the other shrunk, depending on the chosen $M$. A value $M = M_{c}$ was found at which the position of the phase junction fluctuated in both directions without any discernible growth of either phase. The respective grain composition, $c = 0.02$ at.%Ag, was identified with the GB phase equilibrium at this temperature. The phase change occurring at this composition is accompanied by a jump in Ag segregation marked by the vertical dashed line in Fig. 4(f). This calculation gives a point on the temperature-composition phase diagram shown in Fig. 4(g).

Similar calculations at other temperatures would recover the entire phase coexistence line on this diagram.

The obtained phase coexistence point was used as a reference state for thermodynamic integration. Fig. 4(e) shows the free energies of the GB phases relative to this reference state, $\gamma_{SK} - \gamma_{c}$, and $\gamma_{SK} - \gamma_{c}$, as functions of the grain composition. Note that the free energy difference between the phases, $\gamma_{SK} - \gamma_{SK}$, is very small. Even when extrapolated to pure Cu at 900 K, it reaches only 2.2 ml/m$^2$. This is much smaller than typical GB energies in metals (e.g., 951 ml/m$^2$ for this boundary at 0 K). The free energy difference $\gamma_{SK} - \gamma_{SK}$ is the driving force for the GB phase transformation per unit area. Its small magnitude demonstrates that, applying the proposed simulation method, thermodynamic properties of individual GB phases can be computed with a high precision, including accurate location of GB phase transformation points. The ability to evaluate the driving force for GB transitions is crucial for the understanding of nucleation and growth of GB phases. For example, knowing the driving force and measuring the rate of GB phase growth, the mobility of the GB phase junction can be extracted. Kinetic properties of this novel line defect are presently unknown.

4. Effect of grain boundary transformations on kinetic properties

4.1. Effect on grain boundary motion

The recent experimental studies of the effect of GB transitions on grain growth kinetics [1,13] utilized polycrystalline samples
and could only provide information related to collective behavior and properties of multiple GBs. Atomistic simulations offer an effective tool for gaining deeper insights by examining the effect of specific, fully characterized, GB phases on kinetic properties of individual GBs. One of the approaches to the evaluation of GB kinetics is to drive a GB by an applied shear stress and extract its mobility from the velocity-force relation [46,47]. The stress-driven GB motion is caused by the shear-coupling effect, in which normal displacements of a boundary are coupled to parallel translations of the grains [48–53]. The degree of coupling is characterized by the coupling coefficient $b = v_{jj}/v$, where $v_{jj}$ is the grain translation velocity and $v$ the GB velocity. For ideal coupling, $b$ is a geometric factor that can be predicted from the GB crystallography. In the particular case of [001] symmetrical tilt GBs, there are two coupling modes with coupling factors $b_{100} = 2\tan(\theta/2)$ and $b_{110} = -2\tan(\pi/4 - \theta/2)$, where $\theta$ is the misorientation angle. These two equations describe the (100) and (110) modes of coupling and were verified by both atomistic simulations [49–51] and experiments on Al bicrystals [53,54].

The previous work on coupled GB motion of $\Sigma 5$ GBs was performed on normal-kite structural units and did not investigate other GB phases. The latter has been done recently using the Cu

Fig. 4. (a) A bicrystal with split-kite and filled-kite GB phases of the $\Sigma 5$[210](001) GB in Cu(Ag) alloy connected to open surfaces [37]. Zoomed-in views of the split-kite (b) and filled-kite (c) structures reveal bilayer and monolayer segregation patterns, respectively. (d and f) Segregation isotherms calculated for the two phases at 900 K. (e) GB free energies relative to the phase coexistence state with $c_\gamma = 0.02\%$. (g) Schematic of the phase coexistence line $c_\gamma(T)$ [38].
The split-kite and filled-kite phases of this boundary were created in simulation blocks that did not contain sinks or sources of atoms, which precluded phase transformations. A shear stress was applied to each boundary employing the previous methodology. As illustrated in Fig. 5(a and b), under the same shear rate, the two GB phases move in opposite directions and with different speeds. To quantify this difference, the inverse coupling factors computed for the two phases are plotted as functions of temperature in Fig. 5(c). Until the temperature reaches about 0.83Tm, both phases move with ideal coupling factors but in different coupling modes: split kites in the (100) mode (β > 0) while filled kites in the (110) mode (β < 0). This behavior demonstrates that GB phase transformations can have a strong impact on GB migration. It suggests that in some cases, a phase transformation can even reverse the direction of GB motion by triggering a switch between different coupling modes. Thus, a possible indirect way to discover GB phase transitions is by measuring variations in the coupling factor at different temperatures and impurity levels.

At temperatures above 0.83Tm, the coupling factors of both GB phases become non-ideal. The motion of the filled-kite phase is accompanied by an increasing number of sliding events until the boundary completely pre-melts at 1300 K and its response to the applied shear switches to pure sliding (β \( \propto \)). The split-kite phase also becomes increasingly disordered; its coupling factor becomes non-ideal and at about 1200 K changes sign. The shear stress required for sustaining the GB motion with a given velocity decreases with temperature (Fig. 5(d)). At high temperatures when the boundary becomes atomically disordered, the stress approaches zero. It is interesting to note that the stress required to move the filled-kite phase is about 60% of that for the split-kite phase. This observation suggests that, under a given driving force, a GB phase transition can significantly accelerate, slow down or even stop the GB motion.

4.2. Effect on grain boundary diffusion

GB diffusion is a structure-sensitive property. It is natural to expect that structural phase transformations in GBs can have a significant impact on GB diffusivity. Fig. 6 shows an Arrhenius plot, \( \log P \text{ versus } 1/T \), of the calculated GB diffusion flux \( P = D_{gb} \delta \). Here, \( D_{gb} \) is the GB self-diffusion coefficient in the Cu \( \Sigma 5(210)[001] \) GB and \( \delta \) is the GB width. The calculations were performed in a periodic simulation block prohibiting GB phase transformations. The diffusion flux was computed from mean-square displacements of GB atoms during MD simulations. Note that the split-kite phase is characterized by a smaller activation energy of diffusion in comparison with the normal-kite phase. The transition between the two phases occurs at approximately 800 K, with the normal-kite phase being more stable below this temperature and the split-kite phase above. Fig. 6 suggests that the phase transition must be accompanied by a characteristic break in the Arrhenius dependence of \( P \) at around 800 K, with a lower activation energy at higher temperatures. This type of a break was indeed observed experimentally at about 800 K. This agreement strongly suggests that the unusual diffusion behavior found in experiments was indeed caused by the phase transformation in this boundary.

In a more recent study, Divinski and co-authors measured Ag impurity diffusivity in the Cu \( \Sigma 5(310) \) GB. The GB diffusivity was described by the diffusion flux \( P = D_{gb}s\delta \), where \( D_{gb} \) is the GB diffusion coefficient of Ag and \( s \) is the impurity segregation factor. Similar to the self-diffusion case, a characteristic break in the Arrhenius dependence of \( P \) was found at about 800–850 K. To make a one to one comparison with the experimental findings, the same diffusion flux was computed for Ag diffusion in the individual kite and split-kite phases of this boundary by combining MD with MC simulations. The latter was applied to create the equilibrium GB segregation of Ag in each phase and to extract the segregation factor \( s \) in the dilute
regime. The results have revealed a break in the slope of the Arrhenius plot at about 800 K (Fig. 6), which is strikingly similar to the break observed in the experiment [39]. This close agreement provides additional confirmation that the non-Arrhenius diffusion behavior found by Divinski et al. [39] was caused by a GB phase transformation. The computed segregation factors were also in good agreement with experimental measurements [39], lending additional credence to the simulation results.

5. Outlook

The concept of interface phase transformations has been known since many years [17,18,56–58]. In fact, the idea can be traced back to Gibbs [59]. The recent explosion of interest in the topic is primarily due to the appearance of new experimental evidence (although mostly indirect) for the existence of such transitions and their possible impact on materials properties. Significant progress has also been achieved in theoretical description of interface transitions [14,17] and their modeling by continuous methods (such phase-field approaches [15,16]) and atomistic simulations [22,37,38,60]. Many theoretical and computational challenges remain in this field. The current thermodynamic theory of interface phase transformations [14] relies on simplifying assumptions that make it applicable, strictly speaking, only to isotropic systems such as multicomponent fluids. The next challenge is to generalize the theory to interfaces between solid phases. Such interfaces are often anisotropic and their properties may depend on the crystallographic orientation of the interface plane. Furthermore, solid–solid interfaces possess two types of tension: the interface free energy and the interface stress, which are different quantities both conceptually and numerically [45,59]. The theory also neglects the curvature effects on interface transformations. Incorporation of these effects would enable applications of the theory to a wider range of real materials.

One aspect that deserves special attention is related to the properties and role of the one-dimensional “phase boundaries”, i.e., junctions between interface phases. Understanding of these defects is crucial for developing theories of phase nucleation at interfaces and description of heterogeneous (multi-phase) states that may exist at interfaces under certain constraints. The recently proposed thermodynamic theory of such junctions should be extended to solid–solid interfaces, such as GBs (especially asymmetric type). In particular, the role of the elastic strain fields created by the phase junctions should be investigated and, if necessary, incorporated in the theory.

On the computational side, the search for interface phases remains a difficult task even in the simplest case of single-component interfaces with a high symmetry. Clearly, the traditional approach to creating interfaces by simply joining two crystals and applying relative rigid translations and local atomic displacements is insufficient for this purpose [32–36,61,62]. The recently proposed simulation methodologies [22,37,38,60] create grand-canonical environments in which the atomic density in the interface regions becomes an additional automatically adjustable parameter leading to a deeper minimization of the interface free energy. However, such methodologies have certain limitations (e.g., the reliance on sufficiently fast GB diffusion) and are only implemented in specifically-designed simulation software. An important task for the future is the development of more robust grand-canonical methods and their implementation in commonly used MD and MC simulation packages. More efficient and accessible simulation approaches would enable computational discovery of new interface phases and deeper investigation of their junctions and multi-phase interface states. This would also provide a broader testing ground for the existing theories and inspiration for future new theories of interface phase transformations.

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